# PNP Epitaxial Silicon Transistor

# **BSR16**

#### **PNP General Purpose Amplifier**

- This Device Designed for Use as General Purpose Amplifier and Switches Requiring Collector Currents to 500 mA
- Sourced from Process 63
- See BCW68G for Characteristics

## **ABSOLUTE MAXIMUM RATINGS**

(T<sub>A</sub> = 25°C, unless otherwise specified.)

Symbol	Parameter	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	-60	V
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5.0	V
I <sub>C</sub>	Collector Current - Continuous	-800	mA
T <sub>J</sub> , T <sub>ST</sub>	Operating and Storage Junction Temperature Range	−55 ~ +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### THERMAL CHARACTERISTICS

(T<sub>A</sub> = 25°C, unless otherwise specified)

Symbol	Parameter	Max.	Unit
$P_{D}$	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{ heta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

3. Device mounted on FR-4 PCB 40 mm × 40 mm × 1.5 mm.



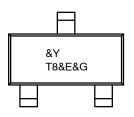
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SOT-23 CASE 318BM

#### **MARKING DIAGRAM**

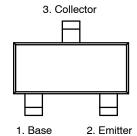


&Y ON Semiconductor Logo T8 Specific Device Code

&E Designates Space

&G Date Code (Week)

## **PIN ASSIGNMENT**



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BSR16	SOT-23 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## **BSR16**

## $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_A = 25^{\circ}C, \ unless \ otherwise \ specified)$

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
OFF CHARA	CTERISTICS	•				-
BV <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = -10$ mA, $I_{\rm B} = 0$	-60			V
BV <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-60			V
BV <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = -10 \mu A, I_C = 0$	-5.0			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -50 V V <sub>CB</sub> = -50 V, T <sub>A</sub> = 150°C			-10 -10	nA μA
I <sub>CEX</sub>	Collector Cut-off Current	$V_{CE} = -30 \text{ V}, V_{EB} = -0.5 \text{ V}$			-50	nA
I <sub>BEX</sub>	Reverse Base Current	$V_{CE} = -30 \text{ V}, V_{EB} = -3.0 \text{ V}$			-50	nA
ON CHARAC	CTERISTICS					
h <sub>FE</sub>	DC Current Gain	$\begin{split} I_C &= -0.1 \text{ mA, } V_{CE} = -10 \text{ V} \\ I_C &= -1.0 \text{ mA, } V_{CE} = -10 \text{ V} \\ I_C &= -10 \text{ mA, } V_{CE} = -10 \text{ V} \\ I_C &= -150 \text{ mA, } V_{CE} = -10 \text{ V} \\ I_C &= -500 \text{ mA, } V_{CE} = -10 \text{ V} \end{split}$	75 100 100 100 50	300		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -150 \text{ mA}, I_B = -15 \text{ mA}$ $I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$			-0.4 -1.6	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = -150 \text{ mA}, I_B = -15 \text{ mA}$ $I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$			-1.3 -2.6	V
SMALL SIGN	NAL CHARACTERISTICS					
f <sub>T</sub>	Current Gain Bandwidth Product	$I_C = -50$ mA, $V_{CE} = -20$ V, $f = 100$ MHz, $T_A = 25$ °C	200			MHz
C <sub>cb</sub>	Output Capacitance	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1.0 MHz			8.0	pF
C <sub>eb</sub>	Emitter-Base Capacitance	$V_{CB} = -2.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$			30	pF
SWITCHING	CHARACTERISTICS					
t <sub>on</sub>	Turn-On Time	$V_{CC} = -30 \text{ V, } I_{C} = -150 \text{ mA,}$ $I_{B1} = -15 \text{ mA}$			45	ns
t <sub>d</sub>	Delay Time				10	ns
t <sub>r</sub>	Rise Time				40	ns
t <sub>off</sub>	Turn-Off Time	$V_{CC} = -6 \text{ V}, I_{C} = -150 \text{ mA},$			100	ns
t <sub>s</sub>	Storage Time	$I_{B1} = I_{B2} = -15 \text{ mA}$			80	ns
t <sub>f</sub>	Fall Time				30	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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